

Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company





PNP SILICON PLANAR EPITAXIAL SWITCHING TRANSISTORS

2N3905 / 2N3906



TO-92
Plastic Package
For Lead Free Parts, Device
Part # will be Prefixed with
"T"

General Purpose Switching And Amplifier Applications

ABSOLUTE MAXIMUM RATINGS (T_a=25°C)

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Emitter Voltage	V _{CEO}	40	V
Collector Base Voltage	V _{CBO}	40	V
Emitter Base Voltage	V _{EBO}	5.0	V
Collector Current Continuous	I _C	200	mA
Power Dissipation T _a =25°C	P _D	625	mW
Derate Above 25°C		5.0	mW/ºC
Power Dissipation T _a =60°C	P _D	250	mW
Power Dissipation T _c =25°C	P _D	1.5	W
Derate Above 25ºC		12	mW/ºC
Operating And Storage Junction Temperature Range	T_{j},T_{stg}	-55 to +150	°C
THERMAL RESISTANCE			
Junction to Case	R _{th (j-c)}	83.3	°C/W
Junction to Ambient in free air	Rth _(j-a)	200	°C/W

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

ELECTRICAL CHARACTERISTICS (T _a =25°C unless specified otherwise)							
DESCRIPTION	SYMBOL	YMBOL TEST CONDITION		2N3906	UNITS		
Collector Emitter Voltage	V_{CEO}	$I_C=1$ mA, $I_B=0$	>40	>40	V		
Collector Base Voltage	V_{CBO}	I _C =10μΑ. I _E =0	>40	>40	V		
Emitter Base Voltage	V_{EBO}	$I_{E}=10\mu A,\ I_{C}=0$	>5.0	>5.0	V		
Collector Cut Off Current	I _{CEX}	V_{CE} =30V, V_{EB} =3V	< 50	< 50	nA		
Base Cut Off Current	I _{BL}	V_{CE} =30V, V_{EB} =3V	< 50	< 50	nA		
DC Current Gain	*h _{FE}	$I_C=0.1$ mA, $V_{CE}=1$ V	>30	>60			
		$I_C=1$ mA, $V_{CE}=1$ V	>40	>80			
		$I_C=10mA, V_{CE}=1V$	50-150	100-300			
		$I_C=50$ mA, $V_{CE}=1$ V	>30	>60			
		$I_C=100$ mA, $V_{CE}=1$ V	>15	>30			
Collector Emitter Saturation Voltage	*V _{CE (sat)}	I _C =10mA, I _B =1mA	< 0.25	< 0.25	V		
		$I_C=50$ mA, $I_B=5$ mA	< 0.40	< 0.40	V		
Base Emitter Saturation Voltage	*V _{BE (sat)}	$I_C=10mA$, $I_B=1mA$	0.65 - 0.85	0.65 - 0.85	V		
		$I_C=50$ mA, $I_B=5$ mA	< 0.95	< 0.95	V		

*Pulse Condition: =300ms, Duty Cycle=2%

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ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

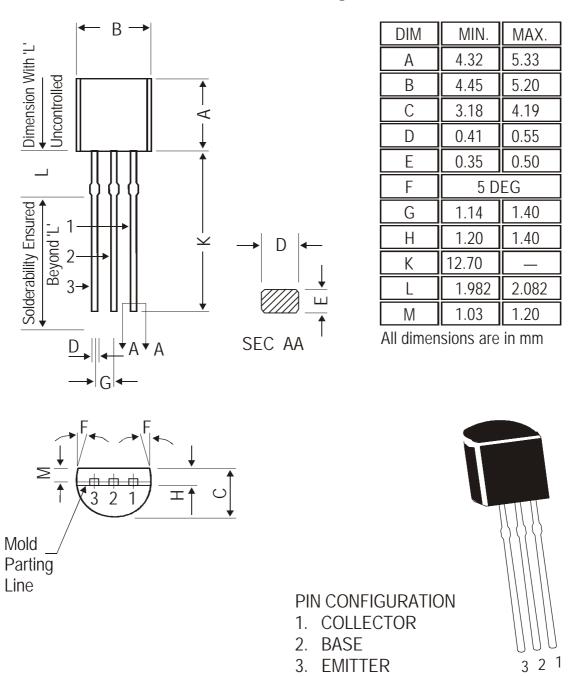
SMALL SIGNAL CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	2N3905	2N3906	UNITS
Transistors Frequency	f _T	I_C =10mA, V_{CE} =20V, f=100MHz	>200	>250	MHz
Output Capacitance	C _{ob}	V_{CB} =5V, I_E =0, f=100KHz	< 4.5	<4.5	pF
Input Capacitance	C _{ib}	V_{EB} =0.5V, I_{C} =0, f=100KHz	<10	<10	pF
		ALL f=1kHz			
Small Signal Current Gain	h_{fe}	$I_C=1$ mA, $V_{CE}=10$ V	50 - 200	100 - 400	
Input Inpedence	h _{ie}	$I_C=1$ mA, $V_{CE}=10$ V	0.5 - 8.0	2.0 -12	kΩ
Out put Adimttance	h _{oe}	$I_C=1$ mA, $V_{CE}=10$ V	1.0 - 40	3.0 - 60	μmhos
Voltage Feedback Ratio	h _{re}	$I_C=1$ mA, $V_{CE}=10$ V	0.1 - 5.0	0.1 - 10	x10 ⁻⁴
Noise Figure	NF	I_{C} =100 μ A, V_{CE} =5V, f=10Hz to 15.7 KHz, R_{S} =1K Ω < 5.0		< 4.0	dB
SWITCHING Time					
Delay time	t_d	V_{CC} =3V, V_{BE} =0.5V	/ < 35 <		ns
Rise time	t _r	I _C =10mA, I _{B1} =1mA	< 35	< 35	ns
Storage time	t _s	$V_{CC}=3V$, $I_{C}=10mA$	< 200	< 225	ns
Fall time	t _f	$I_{B}1=1_{B2}=1$ mA	< 60 < 75 ns		ns

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The TO-92 Package, Tape and Ammo Pack Drawings are correct as on the date of issue/revision of this Data Sheet.

The currently valid dimensions and information, may please be confirmed from the TO-92 Drawing in the Packages and Packing Section of the Product Catalogue.

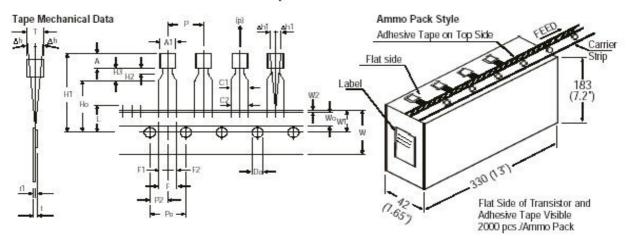
Packing Details

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	GrWt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

TO-92 Plastic Package

For Lead Free Parts, Device Part # will be Prefixed with

TO-92 Tape and Ammo Pack



All dimensions are in mm

		SPECIFICATION			ON			
ITEM	SYMBOL	MIN.	NOM.	MAX.	TOL.	1		
BODY WIDTH	A1	4.45		5.20	Ÿ	NOTES		
BODY HEIGHT	Α	4.32		5.33		Maximum alignment deviation between		
BODY THICKNESS	T	3.18		4.19		leads will not to be greater than 0.2mm		
PITCH OF COMPONENT	P		12.7		± 1.0	Maximum non-cumulative variation		
*1FEED HOLE PITCH	Po		12.7		± 0.3	between tape feed holes shall not		
*2 FEED HOLE CENTRE TO	100.00		10000000			exceed 1 mm in 20 pitches.		
COMPONENT CENTRE	P2		6.35		± 0.4	3. Holddown tape will not exceed beyond		
DISTANCE BETWEEN OUTER LEADS	E		5.08		+ 0.6	the edge(s) of carrier tape and there shall be no exposure of adhesive.		
*3 COMPONENT ALIGNMENT SIDE VIEW	Δh		0	1.0		4. There will be no more than three (3)		
*4 COMPONENT ALIGNMENT FRONT VIEW	Δh1		0	1.3		consecutive missing components in a		
TAPE WIDTH	w		18	96000	± 0.5	tape.		
HOLD-DOWN TAPE WIDTH	Wo		6		± 0.2	A tape trailer, having at least three feed		
HOLE POSITION	W1		9		+ 0.7	holes are provided after the last component in a tape.		
HOLD-DOWN TAPE POSITION	W2	0.0		0.7	10000	6. Splices should not interfere with the		
LEAD WIRE CLINCH HEIGHT	Ho	No area	16	11010330	± 0.5	sprocket feed holes.		
COMPONENT HEIGHT	H1		1000	24.0				
LENGTH OF SNIPPED LEADS	Ľ			11.0				
FEED HOLE DIAMETER	Do		4		± 0.2	REMARKS		
*5 TOTAL TAPE THICKNESS	t			1.2				
LEAD - TO - LEAD DISTANCE	F1, F2	2.40		2.70		*1 Cumulative pitch error 1.0 mm/20 pitch		
STAND OFF	H2	0.45		1.45	- 0.1	*2 To be measured at bottom of clinch		
CLINCH HEIGHT	Н3			3.0		*3 At top of body		
LEAD PARALLELISM	C1 - C2			0.22		*4 At top of body		
PULL - OUT FORCE	(p)	6N		1000000000		*5 t1 0.3 - 0.6 mm		

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

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Customer Notes 2N3905 / 2N3906

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Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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